### DESCRIPTION

The SPN1012 is the N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

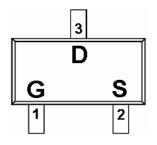
#### APPLICATIONS

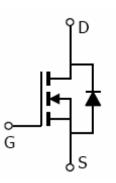
- Drivers : Relays/Solenoids/Lamps/Hammers
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

### FEATURES

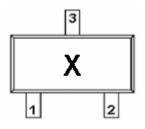
- N-Channel
  20V/0.65A,RDs(ON)=280mΩ@VGs=4.5V
  20V/0.55A,RDs(ON)=300mΩ@VGs=2.5V
  20V/0.45A,RDs(ON)=380mΩ@VGs=1.8V
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- SOT-523 (SC-89) package design

### PIN CONFIGURATION(SOT-523/SC-89)





### PART MARKING





PIN DESCRIPTION					
Pin	Symbol	Description			
1	G	Gate			
2	S	Source			
3	D	Drain			

### **ORDERING INFORMATION**

Part Number	Package	Part Marking
SPN1012S52RG	SOT-523	Х

X SPN1012S52RG : Tape Reel ; Pb – Free

## ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		VDSS	20	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Drain Current( $T_{1}=150^{\circ}$ C)	TA=25°C	ID	0.65		
Continuous Drain Current(TJ=150°C)	Та=80°С	ID	0.45	— A	
Pulsed Drain Current		Idm	1.0	Α	
Continuous Source Current(Diode Conduction)		Is	0.3	Α	
Derver Dissignation	TA=25°C	Dr	0.27	W	
Power Dissipation	Та=70°С	PD	0.16	- W	
Operating Junction Temperature		TJ	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	

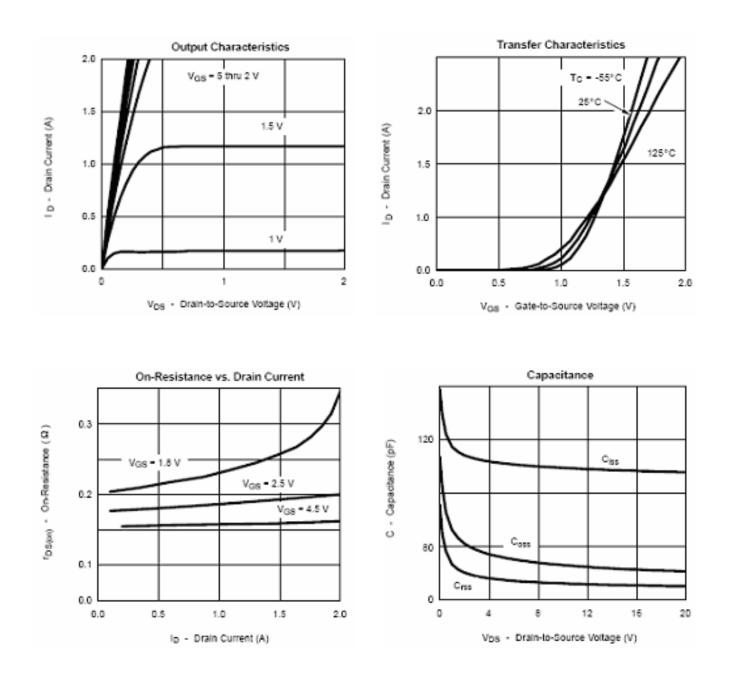


## ELECTRICAL CHARACTERISTICS

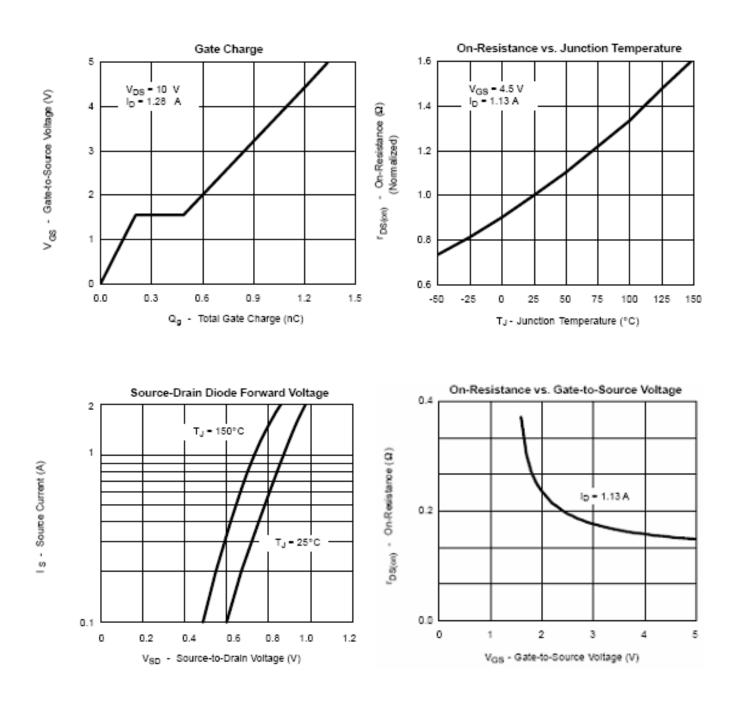
(TA=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static		·				
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID= 250uA	20			v
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.35		0.8	- V
Gate Leakage Current	IGSS	VDS=0V,VGS=±12V			100	nA
Zero Gate Voltage Drain Current	Idss	$\frac{V_{DS}=20V,V_{GS}=0V}{V_{DS}=20V,V_{GS}=0V}$ $T_{J}=55^{\circ}C$			1 5	uA
On-State Drain Current	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 5V$	0.7			А
Drain-Source On-Resistance	RDS(on)	VGS=4.5V,ID=0.65A VGS=2.5V,ID=0.55A VGS=1.8V,ID=0.45A		0.20 0.22 0.28	0.28 0.30 0.38	Ω
Forward Transconductance	gfs	VDS=10V,ID=0.4A		1.0		S
Diode Forward Voltage	Vsd	Is=0.15A,VGs=0V		0.8	1.2	V
Dynamic						
Total Gate Charge	Qg	VDS=10V,VGS=4.5V,		1.2	1.5	nC
Gate-Source Charge	Qgs	ID≡0.6A		0.2		
Gate-Drain Charge	Qgd			0.3		
Turn-On Time	td(on)	$V_{DD}=10V,R_{L}=10\Omega$		5	10	- ns
	tr	$ID=10^{\circ}, RL=1052^{\circ}, ID=0.5A$		8	15	
	td(off)	VGEN= $4.5V$ , RG= $6\Omega$		10	18	
Turn-Off Time	tſ	tf		1.2	2.8	

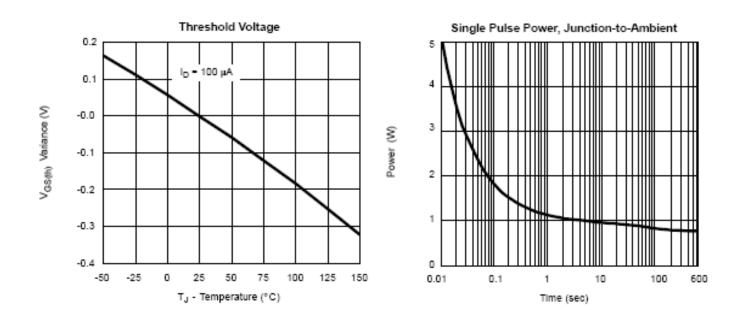
TYPICAL CHARACTERISTICS



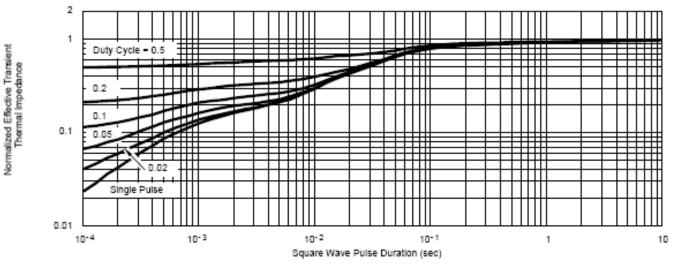
TYPICAL CHARACTERISTICS



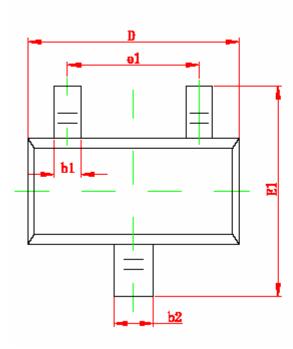
TYPICAL CHARACTERISTICS

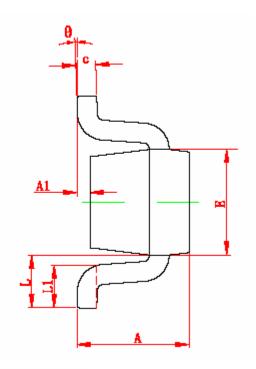


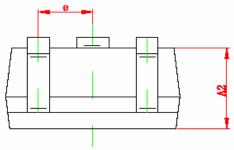
Normalized Thermal Transient Impedance, Junction-to-Foot



## SOT-523 PACKAGE OUTLINE







Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
A	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.325	0.010	0.013	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
E	0.750	0.850	0.030	0.033	
E1	1.450	1.750	0.057	0.069	
e	0.500 TYP		0.020	) TYP	
e1	0.900	1.100	0.035	0.043	
L	0.550 REF		0.022 REF		
L1	0.280	0.440	0.011	0.017	
θ	0°	4°	0°	4°	



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